

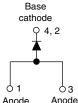
Vishay Semiconductors

COMPLIANT **HALOGEN**

FREE

Schottky Rectifier, 5.5 A





D-PAK	(TO-252AA)
	(

PRODUCT SUMMARY		
Package	D-PAK (TO-252AA)	
I _{F(AV)}	5.5 A	
V_{R}	100 V	
V _F at I _F	See Electrical table	
I _{RM}	4 mA at 125 °C	
T _J max.	150 °C	
Diode variation	Single die	
E _{AS}	6 mJ	

FEATURES

- · Low forward voltage drop
- · Guard ring for enhanced ruggedness and long term reliability
- Popular D-PAK outline
- · Small foot print, surface mountable
- · High frequency operation
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



The VS-50WQ10FNHM3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

52AA)	Ó 1 Ó 3 Anode Anode	
MMARY		
;	D-PAK (TO-252AA)	
	5.5 A	

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I _{F(AV)}	Rectangular waveform	5.5	А	
V_{RRM}		100	V	
I _{FSM}	t _p = 5 μs sine	330	А	
V _F	5 A _{pk} , T _J = 125 °C	0.63	V	
T _J	Range	- 40 to 150	°C	

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-50WQ10FNHM3	UNITS
Maximum DC reverse voltage	V_{R}	100	V
Maximum working peak reverse voltage	V_{RWM}	100	V

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 135 °C, rectangular waveform		5.5	
Maximum peak one cycle non-repetitive surge current	l	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	330	Α
non-repetitive surge current I _{FSM} See fig. 7		10 ms sine or 6 ms rect. pulse	V _{RRM} applied	110	
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 0.5 \text{A}, L = 40 \text{mH}$		6.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical 0.5		А	



Vishay Semiconductors

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
		5 A	T ₁ = 25 °C	0.77	V
Maximum forward voltage drop	V _{FM} ⁽¹⁾	10 A	1) = 23 0	0.91	
See fig. 1	V _{FM} (·)	5 A	T _J = 125 °C	0.63	
		10 A		0.74	
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V Dated V	1	A
See fig. 2	IRM (''	$T_J = 125 ^{\circ}\text{C}$	V _R = Rated V _R	4	mA
Threshold voltage	V _{F(TO)}	$ T_{J} = T_{J} \text{ maximum} $ $ 0.47 $ $ 21.46 $		0.47	V
Forward slope resistance	r _t			mΩ	
Typical junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz), 25 °C 183		pF	
Typical series inductance	L _S	Measured lead to lead 5 mm from package body 5.0		nΗ	

Note

 $^{(1)}\,$ Pulse width $<300~\mu s,$ duty cycle <2~%

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 40 to 150	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	3.0	°C/W
Approximate weight			0.3	g
Approximate weight			0.01	OZ.
Marking device		Case style D-PAK	50WQ	10FNH

Note

$$^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$$

www.vishay.com

Vishay Semiconductors

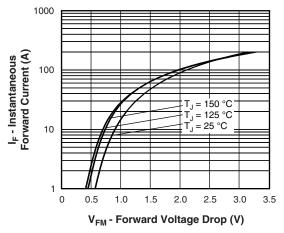


Fig. 1 - Maximum Forward Voltage Drop Characteristics

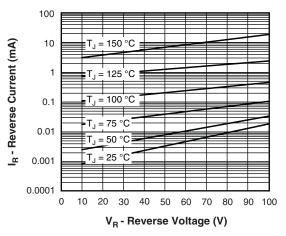


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

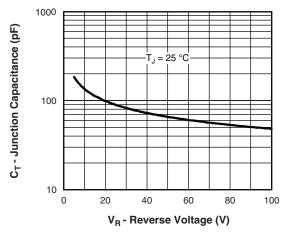


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

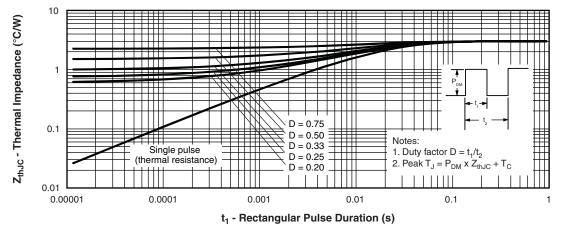


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



www.vishay.com

Vishay Semiconductors

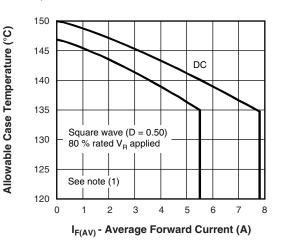


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

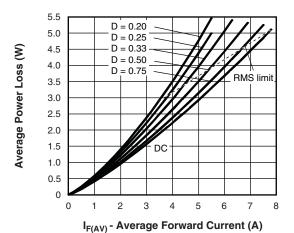


Fig. 6 - Forward Power Loss Characteristics

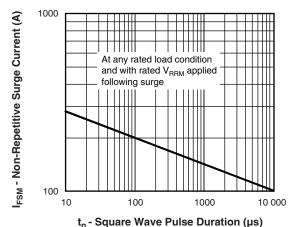


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

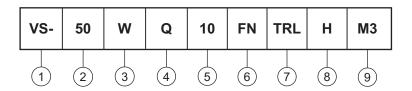
 $\begin{array}{l} \text{(1)} \ \ \text{Formula used:} \ T_C = T_J - (Pd + Pd_{REV}) \ x \ R_{thJC}; \\ Pd = Forward \ power \ loss = I_{F(AV)} \ x \ V_{FM} \ at \ (I_{F(AV)}/D) \ (see \ fig. \ 6); \\ Pd_{REV} = Inverse \ power \ loss = V_{R1} \ x \ I_R \ (1 - D); \ I_R \ at \ V_{R1} = 80 \ \% \ rated \ V_R \ \text{(1)} \\ \end{array}$



Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (5.5 A)

3 - Package identifier:

W = D-PAK

4 - Schottky "Q" series

Voltage rating (10 = 100 V)

6 - FN = TO-252AA (D-PAK)

7 - • None = Tube

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

8 - H = AEC-Q101 qualified

9 - Environmental digit:

M3 = Halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-50WQ10FNHM3	75	3000	Antistatic plastic tube		
VS-50WQ10FNTRHM3	2000	2000	13" diameter reel		
VS-50WQ10FNTRRHM3	3000	3000	13" diameter reel		
VS-50WQ10FNTRLHM3	3000	3000	13" diameter reel		

LINKS TO RELATED DOCUMENTS		
Dimensions <u>www.vishay.com/doc?95519</u>		
Part marking information	www.vishay.com/doc?95518	
Packaging information	www.vishay.com/doc?95033	



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.